



Sinomags Product Datasheet

CURRENT SENSOR

PRODUCT SERIES: STB-LA/N1

STB-25LA/N1

PRODUCT PART NUMBER: STB-50LA/N1
STB-100LA/N1

VERSION: Ver 1.2



Sinomags Technology Co., Ltd.

Web site: www.sinomags.com

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1. Description

STB-LA series current sensors are based on close loop principle with TMR technology. The sensor can detect the current with DC, AC, pulse and irregular wave shape.

Typical application

- Solar inverter
- Direct-current dynamo
- Switched model power supplies (SMPS)
- BMS
- Solar inverter

General parameters

Parameter	Symbol	Unit	Value
Working temperature	T_A	°C	-40 ~ 85
Storage temperature	T_stg	°C	-40 ~ 95
STB-100LA/N max secondary Coil Res.@25°C	Rs	Ω	65
STB-100LA/N max secondary Coil Res.@85°C	Rs	Ω	85
STB-100LA/N1 max secondary Coil Res.@25°C	Rs	Ω	18
STB-100LA/N1 max secondary Coil Res.@85°C	Rs	Ω	25
Mass	m	g	28

Maximum effective value

Parameter	Symbol	Unit	Value
Supply voltage (non demolition)	V_C	V	±16
ESD Class (HBM)	U_ESD	kV	4

Remark: the unrecoverable damage may occur when the product works on the conditions over the absolute maximum ratings. Long-time working on the absolute maximum ratings may cause the degradation on performance and reliability.

Isolation parameters

Parameter	Symbol	Unit	Value	Remark
RMS voltage for AC test 50Hz/1 min	Ud	kV	5	
Impulse withstand voltage 1.2/50μs	Üw	kV	10	
Clearance distance (pri. -sec)	dCl	mm	13	Shortest distance through air
Creepage distance (pri. -sec)	dCp	mm	13	Shortest path along device body
Case material			V0 according to UL 94	

2. STB-25LA/N1 Electrical parameters

Condition: $V_{cc} = \pm 15V$, $RL = 10 k\Omega$, $T_A = 25^\circ C$, unless specified.

Parameters	Symbol	Unit	Min.	Typ.	Max.	Remark
Primary nominal rms current	I_pn	A		25		
Primary current measuring range	I_pm	A	-55		55	Remark1
Supply voltage	Vcc	V	± 12		± 15	
Secondary Coil turns	N_s	N		1000		
Sampling resistance SPEC	R_m	Ω	0	33	200	
Secondary Coil Rated output current	I_sn	mA		25		
Consumption current	Icc	mA		$10 + I_s$		$I_s = \text{ABS}(I_p / N_s)$
Sensitivity error	X	%			± 0.5	within I_pn
Linearity error within I_pn	ξ_L	% of I_pn			± 0.10	
offset	I_OE	mA			± 0.10	@ $I_p = 0 A$
Magnetic bias current	I_OM	mA			± 0.25	$3 * I_{pn}$ remanence
Offset Temperature drift	I_OT	mA		± 0.15	± 0.30	$-40^\circ C \sim 85^\circ C$
Reaction time	t_ra	μs			0.3	@10% of I_pn
Step response time (Remark2)	t_res	μs			0.5	@90% of I_pn
-1dB band width	BW	kHz		150		

Remark:

- 1) The maximum test current is 200 A, DC or peak current, $85^\circ C$, $V_{cc} = \pm 12 V$ (tolerance $\pm 0.3 V$), sampling resistor RM $\leq 33 \Omega$. X $\leq 1\%$. If a larger maximum detection current is required, refer to the sampling resistance specification sheet.
- 2) $di/dt = 100A/\mu s$.

3. STB-50LA/N1 Electrical parameters

Condition: $V_{cc} = \pm 15V$, $RL = 10 k\Omega$, $T_A = 25^\circ C$, unless specified.

Parameters	Symbol	Unit	Min.	Typ.	Max.	Remark
Primary nominal rms current	I_pn	A		50		
Primary current measuring range	I_pm	A	-128		128	Remark1
Supply voltage	Vcc	V	± 12		± 15	
Secondary Coil turns	N_s	N		1000		
Sampling resistance SPEC	R_m	Ω	0	33	200	
Secondary Coil Rated output current	I_sn	mA		50		
Consumption current	Icc	mA		$10 + I_s$		$I_s = \text{ABS}(I_p / N_s)$
Sensitivity error	X	%			± 0.5	within I_pn
Linearity error within I_pn	ξ_L	% of I_pn			± 0.10	
offset	I_OE	mA			± 0.10	@ $I_p = 0 A$
Magnetic bias current	I_OM	mA			± 0.25	$3 * I_pn$ remanence
Offset Temperature drift	I_OT	mA		± 0.15	± 0.30	$-40^\circ C \sim 85^\circ C$
Reaction time	t_ra	μs			0.3	@ 10% of I_pn
Step response time (Remark2)	t_res	μs			0.5	@ 90% of I_pn
-1dB band width	BW	kHz		150		

Remark:

- 1) The maximum test current is 200 A, DC or peak current, $85^\circ C$, $V_{cc} = \pm 12 V$ (tolerance $\pm 0.3 V$), sampling resistor RM $\leq 33 \Omega$. X $\leq 1\%$. If a larger maximum detection current is required, refer to the sampling resistance specification sheet.
- 2) $di/dt = 100A/\mu s$.

4. STB-100LA/N1 Electrical parameters

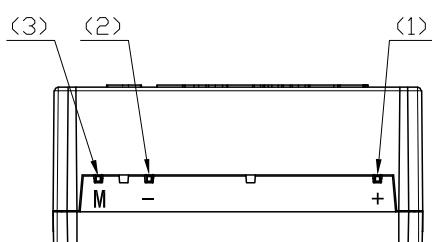
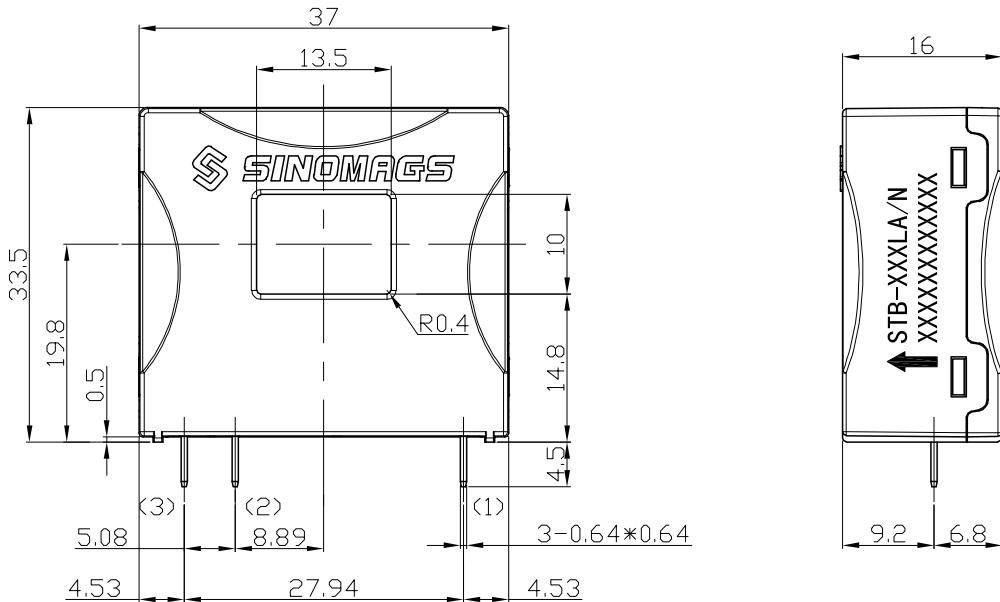
Condition: $V_{cc} = \pm 15V$, $RL = 10 k\Omega$, $TA = 25^\circ C$, unless specified.

Parameters	Symbol	Unit	Min.	Typ.	Max.	Remark
Primary nominal rms current	I_pn	A		100		
Primary current measuring range	I_pm	A	-200		200	Remark1
Supply voltage	Vcc	V	± 12		± 15	
Secondary Coil turns	N_s	N		1000		
Sampling resistance SPEC	R_m	Ω	10		200	
Secondary Coil Rated output current	I_sn	mA		100		
Consumption current	Icc	mA		$10 + I_s$		$I_s = \text{ABS}(I_p / N_s)$
Sensitivity error	X	%			± 0.5	within I_pn
Linearity error within I_pn	ξ_L	% of I_pn			± 0.10	
offset	I_OE	mA			± 0.10	@ $I_p = 0 A$
Magnetic bias current	I_OM	mA			± 0.25	$3 * I_pn$ remanence
Offset Temperature drift	I_OT	mA		± 0.15	± 0.30	$-40^\circ C \sim 85^\circ C$
Reaction time	t_ra	μs			0.3	@ 10% of I_pn
Step response time (Remark2)	t_res	μs			0.5	@ 90% of I_pn
-1dB band width	BW	kHz		150		

Remark:

- 1) The maximum test current is 200 A, DC or peak current, $85^\circ C$, $V_{cc} = \pm 12 V$ (tolerance $\pm 0.3 V$), sampling resistor $R_M \leq 33 \Omega$. $X \leq 1\%$. If a larger maximum detection current is required, refer to the sampling resistance specification sheet.
- 2) $di/dt = 100A/\mu s$.

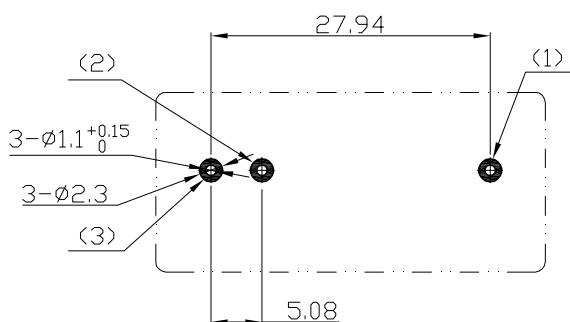
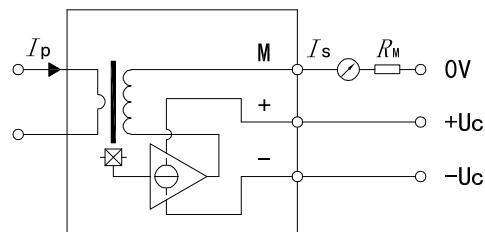
5. STB-LA/N1 Dimensions & Pin define



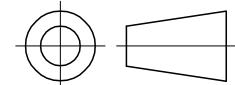
Terminals

(1)	+
(2)	-
(3)	M

Connection



Material : Fit UL94V-0 & RoHS requirements ;
General tolerance : ± 0.5
Unit : mm



Mechanical properties

- General tolerances ± 0.5 mm;
- Fixed connection second coil 3 PIN size is 0.6 * 0.6mm . The recommended diameter of PCB pad is 1.1 mm;